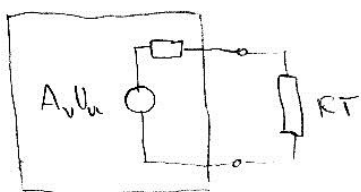


TEORIJA 12.11.2012)

ELE-1 | 18.11.2013

1

1.



$$A_v = 100$$

$$A_v = \frac{U_{12}}{U_u} = A_v = \frac{R_T}{R_1 + R_T}$$

$$A_v = A_v \cdot \frac{R_1 + R_{12}}{R_T} = A_v \left(1 + \frac{R_{12}}{R_1} \right) = 200$$

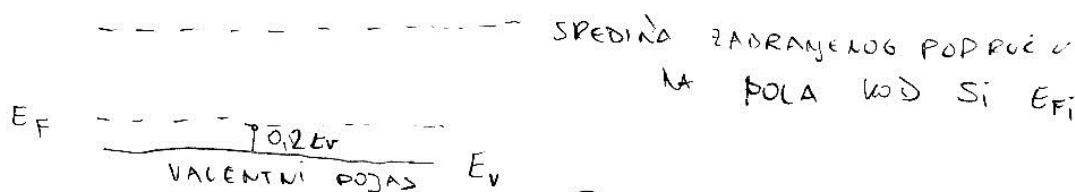
Idealno pojačalo $\rightarrow \underline{R_{12} = 0}$

d) $A_v = 200, R_{12} = 0$

2.

Si

VODLJIVI POJAS



P-TIP, DOPIRANO SA AKCEPTORIMA
JER JE E_F ISPOD SREDNJE Z.P.

Nakon toga si dodatno dopiran E_F ostaje isti

\Rightarrow TA $E_F \rightarrow E_{Fi} \rightarrow$ možemo dopirati da dodavali
primjesa E_F teži E_v tj. da
 E_F ostane isti bez obzira na
povećanje temp
DOPIRAMO AKCEPTORIMA

a) Si P-TIP, AKCEPTORI

TEORIJA (11.11.12)

ELE-1 | 18.11.13

2

③ PN-SPOJ OBUJE USKE STRUJE RAZLIČNO DOPIN $N_A = 1000 N_D$ $N_A \gg N_D$

OSIROMAŠENO PODRUČJE

$$\underline{d_{DP} \ll d_{DN}}$$

DIFUZISKE STRUJE MAJINU

$$p_{DP} \gg n_{DN}$$

$$n_{DP} \ll p_{DN}$$

$$I_{DP} \sim p_{DN} \quad I_{DN} \sim n_{DP}$$

$$\Rightarrow \underline{\underline{I_{DP} \gg I_{DN}}}$$

$$d) \quad I_{DP} \gg I_{DN}, \quad d_{DP} \ll d_{DN}$$

④ LED DIODA

→ KORISTE REKOMBINACIJU

↳ PROPUŠNA POLARIZACIJA

$$\lambda = 690 \text{ nm} = 0,69 \mu\text{m} \quad \left(\begin{array}{l} \text{mora biti} \\ 0,69 \mu\text{m} \end{array} \right)$$

$$\lambda = \frac{1,24}{E_g} \quad E_g = \frac{1,24}{0,69} = \underline{\underline{1,8 \text{ eV}}}$$

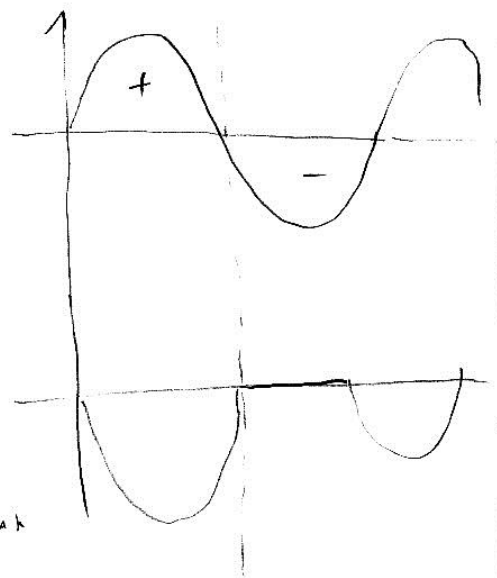
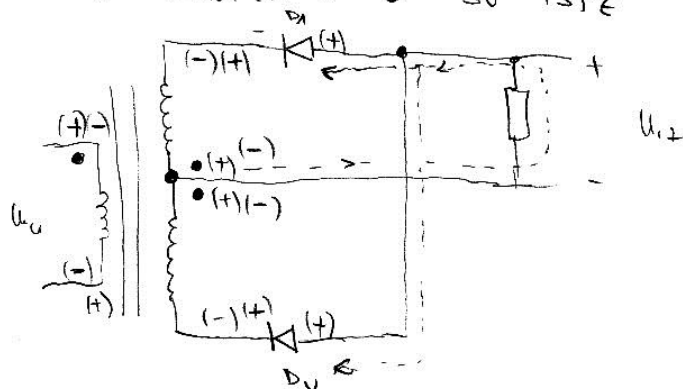
$$d) \quad E_g = 1,8 \text{ eV}, \text{ propusna}$$

TEORIJA (21.11.12)

⑤ ISPRAVLJAČ

→ NA ULAZU SINUS, ANKIZIRAO + i - FAZU

→ FAZE SIGNALA U • SU ISTE



- POLARIZACIJA DODA, PROPUŠNA
ZA POZITIVNI DIO ULAZ (LIJEVA OZNAKA)
- DIODA, ZAPORNA
ZA NEGATIVNI DIO ULAZA (DESA OZNAKA)

e)

6.

SLIKA POPREK PRČ

→ S → L, KANAL FORMIRAN I SUŽAVA SE
ALI NIJE PREKINUT PA JE U TRIODIOM

MOGUĆE A, B, C ... TE TOČKE SU U TRIODIOM

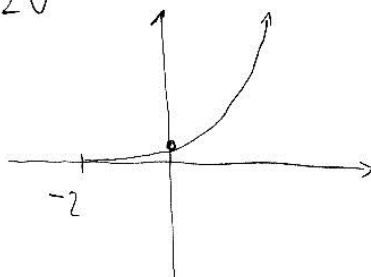
$V_{DS} > 0$ pa nije a jer $V_{DS} = 0$
 nije C jer kanal nije prekinut

TOČKA B $V_{DS} > 0$, TRIODNO PODRUČJE, KANAL NIJE PREKINUT

7. KOJI TIP MOSFET

KAKO V_{GS} POSTAJE POZITIVNI $I_D \uparrow \rightarrow \underline{\underline{N\text{-}MOS}}$

$$V_{GS0} = -2V$$



$$\hookrightarrow V_{GS} = 0V, I_D > 0$$

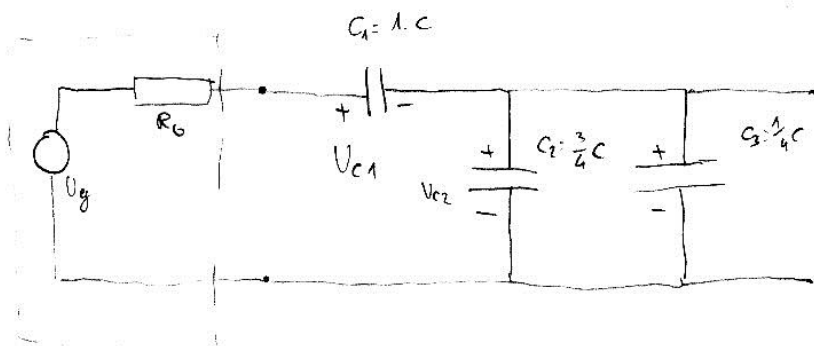
→ OSIROMAŠENI

(C)

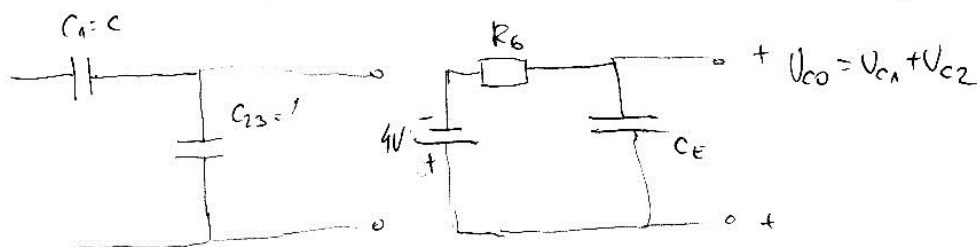
① RC - mreža

- otpor "skriven" u naponskom izvoru

$C = 1 \mu F$



$$U_{C1} = 1V \quad U_{C2} = 1V : U_{C3} \rightarrow \text{početni napon za } \parallel C$$



$$C_{23} = C_2 + C_3 = \frac{3}{4} + \frac{1}{4} = C$$

$$C_E = C_1 \parallel C_{23} = \frac{C}{2}$$

$$U_{C0} = 2V$$

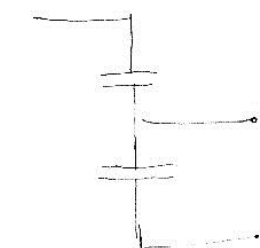
→ pazi na polaritete kondenzatora

$$U_{CP} = 2V \quad U_{CU} = -4V$$

$$0 \leq t \leq \infty$$

$$\tau = R_0 \cdot C_E = 1ms$$

$$\begin{aligned} U_C(t) &= U_{CP} + (U_{CU} - U_{CP}) \left(1 - \exp \frac{-t}{\tau} \right) \\ &= 2 + (-4 - 2) \left(1 - \exp \frac{-t}{\tau} \right) \\ &= -4 + 6 \exp \frac{-t}{\tau} \end{aligned}$$



$$U_{12} = \frac{\frac{1}{C}}{\frac{1}{C} + \frac{1}{C}} U_C = \frac{1}{2} U_C$$

$$U_{12}(t) = \frac{1}{2} U_c(t) = -2 + 3 \exp \frac{-t}{\tau}$$

↑ b)

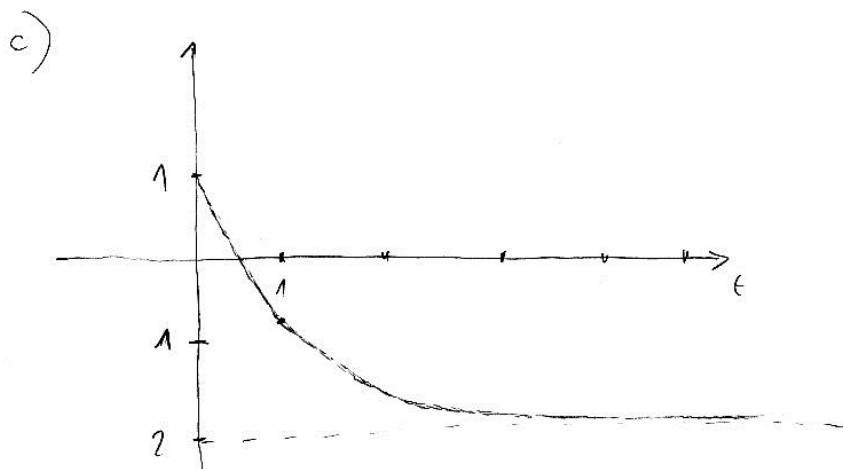
$$U_{12}(t) = -2 + 3 \exp \frac{-t}{\tau}$$

$$U_{12}(0) = -2 + 3 = 1 \text{ V}$$

$$U_{12}(1_{ms}) = -2 + 3 \exp \frac{-1}{1} = \underline{\underline{-0,836 \text{ V}}}$$

$$U_{12}(\infty) = -2 + 3 \exp \frac{-t}{\tau} = \underline{\underline{-2 \text{ V}}}$$

\uparrow
 $t \rightarrow \infty$

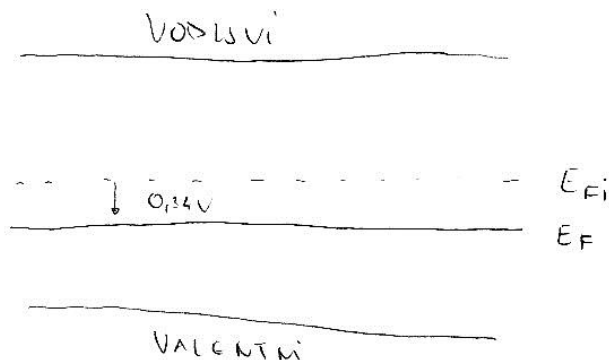


ZADACI (21.11.12)

E(e-1) 18.11.13 7

(2)

Si DOPRAN 1. PRIMJESOM



$$E_{Fi} - E_F = 0,34 \text{ eV}$$

$$\mu_e = 1400 \text{ cm}^2/Vs$$

$$\mu_p = 420 \text{ cm}^2/Vs$$

$$P\text{-TIP}, E_F < E_{Fi}$$

→ DOPRAN AKCEPTORIMA

$$T = 300 \text{ K} \Rightarrow n_i = 1,45 \cdot 10^{10} \text{ cm}^{-3}$$

$$p_0 = n_i \exp \frac{E_{Fi} - E_F}{kT} = 1,45 \cdot 10^{10} \cdot \exp \frac{0,34 \text{ eV}}{\frac{300}{11600}} = 7,43 \cdot 10^{15} \text{ cm}^{-3} \quad \left(\begin{array}{l} \text{većinski nosio} \\ \text{supljivi} \end{array} \right) \quad (N_A)$$

manjinski nosioci u P-TIPU su elektroni.

$$n_0 = \frac{n_i}{p_0} = \frac{1,45 \cdot 10^{10}}{7,43 \cdot 10^{15}} = 2,83 \cdot 10^4 \text{ cm}^{-3} \quad (\text{elektroni})$$

$$p_0 \gg n_i \Rightarrow p_0 \approx N_A \quad \text{DOPRANO AKCEPTORIMA}$$

$$p_0 \gg n_0 \Rightarrow \bar{\nu} \approx \bar{\nu}_p = (\text{koncentracija supljiv.}) = \frac{1}{q \mu_p \cdot p_0} = 0,5 \text{ Si/cm}$$

ZADACI (21.11.12)

ELE-1/12.11.13 8

2 b)

SPEC. VODLJIVOST NA $T = 500\text{ K}$, ISTI MATERIJAL, $T \uparrow$

$$n_i(500\text{ K}) = C_1 T^{\frac{3}{2}} \exp\left(\frac{-E_G}{2kT}\right) = 3,24 \cdot 10^{14} \text{ cm}^{-3}$$

 $n_i \ll N_A$ ekstrinzično TEMP područje

$$p_0 \approx N_A = 7,43 \cdot 10^{15}$$

 \rightarrow KAKO $T \uparrow \rightarrow \mu \downarrow$ (TEMP RASTE, POKRETLJIVOST PADA)

$$\sigma \approx \sigma_p = q \mu_p(500\text{ K}) \cdot p_0 = 1,6 \cdot 10^{-19} \cdot 0,45 \cdot 470 \cdot 7,43 \cdot 10^{15} = 0,45 \cdot \sigma(300\text{ K})$$

$$= \underline{\underline{0,225 \text{ Si/cm}}}$$

ZADACI (21.11.12)

ELE-1/18.11.13 9

③

koncentracija n i p diode

 \Rightarrow n strana: $N_D = 2 \cdot 10^{15} \text{ cm}^{-3}$, manjinski su suplini

Gledaju se manjinski nosioci na N strani

$$\mu_n = 370 \text{ cm}^2/\text{Vs}, \quad \tau_n = 0,8 \mu\text{s} \quad W_n = 0,5 \mu\text{m} = \underline{\underline{0,5 \cdot 10^{-4} \text{ cm}}}$$

 \Rightarrow P strana, Akceptor $N_A = 8 \cdot 10^{17} \text{ cm}^{-3}$
 \rightarrow manjinski nosioci $\mu_n = 700 \text{ cm}^2/\text{Vs} \quad \tau_p = 0,5 \mu\text{s} \quad W_p = 100 \mu\text{m} = \underline{\underline{100 \cdot 10^{-4} \text{ cm}}}$

$$n_{on} \approx N_D = 2 \cdot 10^{15} \text{ cm}^{-3}$$

$$p_{on} \approx \frac{n_i^2}{n_{on}} = 1,05 \cdot 10^5 \text{ cm}^{-3}$$

$$p_{op} \approx N_A = 8 \cdot 10^{17} \text{ cm}^{-3}$$

$$n_{op} = \frac{n_i^2}{p_{op}} = 2,63 \cdot 10^2 \text{ cm}^{-3}$$

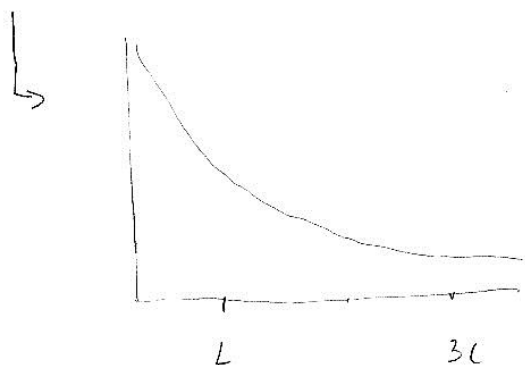
DIFUZISKA DUGJINA NA P STRANI

$$L_p = \sqrt{D_n \cdot \tau_n} = \sqrt{\mu_n \frac{T}{11600} \cdot \tau_n} = 30,09 \cdot 10^{-4} \text{ cm} = 30,09 \mu\text{m}$$

 \rightarrow usporedimo sa $W_p = 100 \mu\text{m} \quad L_p \ll W_p$ (3x jače eksp. osusnost)

$-\frac{x}{L}$	0	-1	-2	-3	-4	-5
$\exp(-\frac{x}{L})$	1	0,368	0,135	0,05	0,018	0,0067

OBJEKTIV PA MOŽEMO ZAKLJUČITI GORE
ŠIROKA STRANA



$W > 3L$
 $W > 5L$ } ŠIROKA STRANA

3) n STRAN

$$L_P = \sqrt{D_P \tau_P} = \sqrt{\mu_P \frac{T}{11600} \tau_P} = 25,75 \mu\text{m} \gg W_n = 0,5 \mu\text{m}$$

USKA STRANA (n)

NA ŠALABAHITEN MAJINSKI NOSIOCI ($S = 0,5 \text{ mm}^2 = 0,5 \cdot 10^{-2} \text{ cm}^2$)

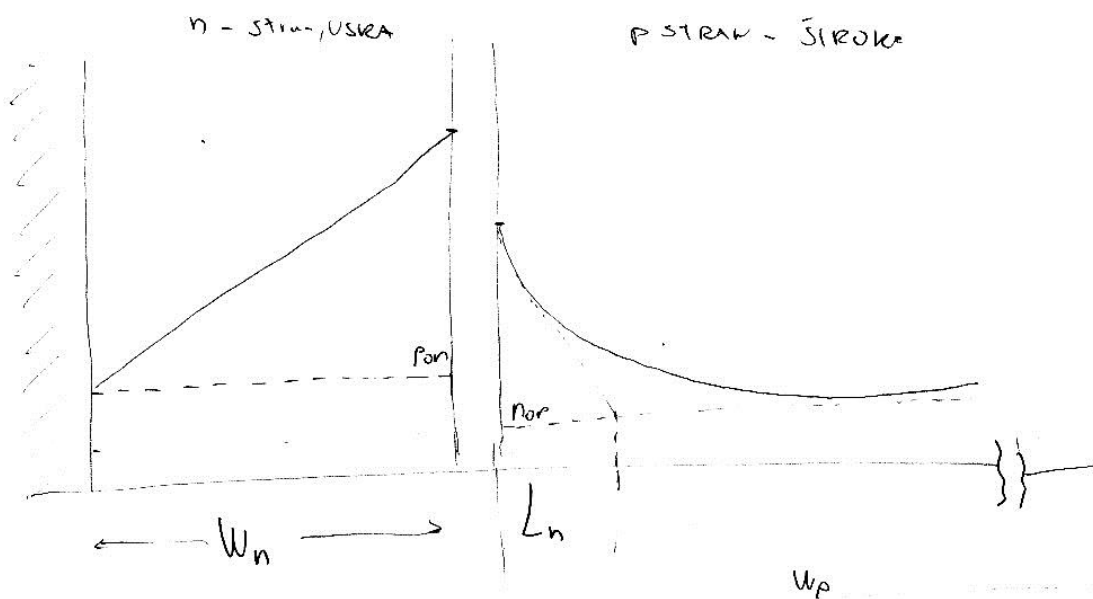
$$a) I_S = I_{Sn} + I_{Sp} = q S \left[\underbrace{D_n \frac{n_{0P}}{L_n}}_{\mu_n V_T} + \underbrace{D_P \frac{p_{0n}}{W_n}}_{\mu_P V_T} \right] = q S \frac{T}{11600} \left[\mu_n \frac{n_{0P}}{L_n} + \mu_P \frac{p_{0n}}{W_n} \right] = \underline{\underline{13,92 \mu\text{A}}}$$

→ GLEDAMO MAJINSKE NOSIOCE NA STRAN

$$3b) I_D = I_S \left(\exp \frac{V_D}{\mu V_T} - 1 \right) \approx I_S \exp \frac{V_D}{\mu V_T} = \underline{\underline{24 \text{ mA}}}$$

$$3c) p_{0n} = 1,05 \cdot 10^5 \text{ cm}^{-3} \Rightarrow p_{n0} = p_{0n} \exp \frac{V_D}{\mu V_T} = 1,91 \cdot 10^6 \text{ cm}^{-3}$$

$$n_{0P} = 2,63 \cdot 10^2 \text{ cm}^{-3} \Rightarrow n_{p0} = n_{0P} \exp \frac{V_D}{\mu V_T} = 4,53 \cdot 10^{11} \text{ cm}^{-3}$$



3 d) Dinamički otpor

→ nagib tangente u radnoj točki, određen derivat

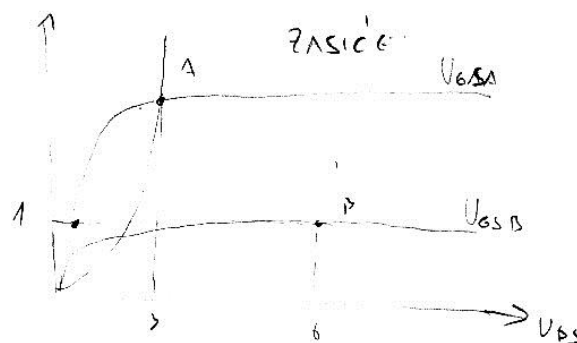
$$r_d = \frac{1}{g_d} = \frac{1}{\left. \frac{\partial I_D}{\partial V_D} \right|_Q} = \frac{1}{I_S \exp \frac{V_D}{mV_T} \cdot \frac{1}{mV_T}} = \frac{mV_T}{\left(I_S \exp \frac{V_D}{mV_T} - I_S \right) + I_S}$$

$$= \frac{mV_T}{I_{DQ} + I_S} \approx \frac{mV_T}{I_{DQ}} = 1 \cdot \frac{300}{11600} \approx \underline{\underline{1,08 \Omega}}$$

4) MOSFET, STATIKA

→ TIP MOSFETA

$$\left. \begin{array}{l} U_{DS} > 0 \\ I_D > 0 \end{array} \right\} \text{N-mos}$$



$$U_{GSA} = -U_{GSB} \Rightarrow \left. \begin{array}{l} U_{GSA} > 0 \\ U_{GSB} < 0 \end{array} \right\} \begin{array}{l} \text{radi uz oba predznaka} \\ \rightarrow \text{OSIROMAJENI TIP Nmos !!} \end{array}$$

b) $I_{DB} = 1 \text{ mA}$, ZASICE (IZ GRAFA)

$$(1) I_{DB} = \frac{k}{2} (U_{GSB} - U_{GS0})^2$$

A) točka na granici TEORNOG ZASICE

$$U_{DS} = U_{GS} - U_{GS0}$$

$$U_{DSA} = 3 \text{ V (IZ GRAFA)}$$

$$(2) U_{GS0} = U_{GSA} - 3 \quad \left. \begin{array}{l} \\ \end{array} \right\} \rightarrow (1)$$

$$(3) U_{GSA} = -U_{GS0}$$

$$I_{DB} = \frac{k}{2} (-U_{GSA} - U_{GSA} + 3)^2 = \frac{k}{2} (2U_{GSA} - 3)^2 \quad \left| \frac{2}{k} \sqrt{\quad} \right.$$

$$2U_{GSA} - 3 = \pm \sqrt{\frac{2I_{DB}}{k}}$$

$$U_{GSA} = 1,5 \pm 0,5 \sqrt{\frac{2I_{DB}}{k}} = 1,5 \pm 0,5 \sqrt{\frac{2 \cdot 1}{2}}$$

$$U_{GSA1} = 2 \text{ V}$$

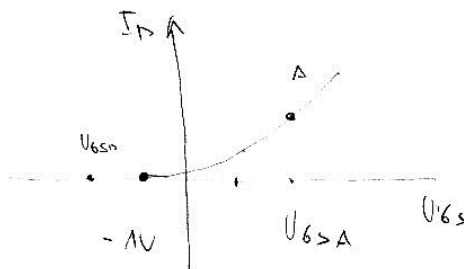
$$U_{GSA2} = 1 \text{ V}$$

} 2 r. 1. SA10 PRILUČITI

$$V_{GS A1} = 2V$$

$$V_{GS O1} = V_{GS A1} - 3 = 2 - 3 = -1V$$

$$V_{GS B1} = -V_{GS A1} = -2V$$



DOBIVEM DA JE UZ $V_{GS B1} = 2V$ $I_D = 0$

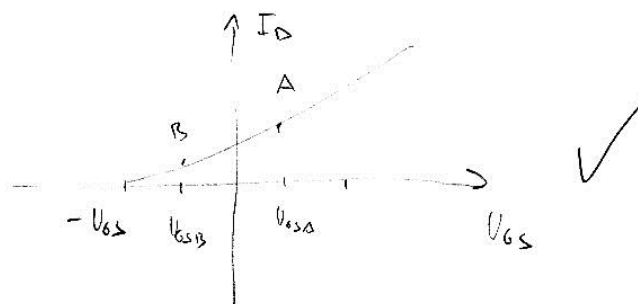
PA NE ODGOVARA ZA PRAVO

KARAKTERISTICI \Rightarrow NIJE PRIHVATLJIVO

$$V_{GS A2} = 1V$$

$$V_{GS O2} = V_{GS A2} - 3 = 1 - 3 = -2V$$

$$V_{GS B2} = -V_{GS A2} = -1V$$



c) $V_{GS} = V_{GS A} = 1V$ $I_D = 1mA$

\Rightarrow TRIODNO RJEŠENJE

$$I_{DC} = k \left[(V_{GS} - V_{GS0}) V_{DS} - \frac{V_{DS}^2}{2} \right]$$

$$\frac{2I_{DC}}{k} = 2(V_{GS} - V_{GS0})V_{DS} - V_{DS}^2$$

$$V_{DS}^2 - 2(V_{GS} - V_{GS0})V_{DS} + \frac{2I_{DC}}{k} = 0$$

$$V_{DS}^2 - 6V_{DS} + 1$$

$$V_{DS1,2} = \frac{6 \pm \sqrt{6^2 - 4}}{2} = V_{DS1} = 5,83V - \text{ZASIĆEN}$$

$$V_{DS2} = \boxed{0,17V - \text{TRIODNO}} \checkmark$$